## NSN 5961-00-079-1318

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-079-1318 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 250.00 milliamperes source cutoff current and 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surface option gold **Precious Material:** Gold **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

Demilitarization:

**Unit Of Measure:** 

No

N/a

## **NSN 5961-00-079-1318** Transistor - Page 2 of 2



Fiig:

A110a0